NSN 5962-01-265-5983

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View Online at https://aerobasegroup.com/nsn/5962-01-265-5983

Body Length:
0.540 inches
Body Width:
0.300 inches
Body Height:
0.092 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and programmable and positive outputs
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
F-9 mil-m-38510
Current Rating Per Characteristic:
100.00 milliamperes forward current, peak total value not applicable
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 flat leads
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

No

Fiig:

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